

WSP6582C

SwitchPro Family High Fidelity Stereo SPDT Switch with Pop and Click Suppression

Descriptions

With *SwitchPro* technology, The WSP6582C is a Dual SPDT analog switch with ultra-low distortion, high OFF-Isolation for special stereo audio applications with negative swing audio signals capacity that features ultra-low Ron of 0.2Ω (typical) at 3.3V VCC.

The WSP6582C operates a single power supply over a wide range from 3.0V to 4.5V and 1.8V logic compatible with ultra high PSRR. With soft-start feature that eliminates pops and clicks associated at any application conditions likes switched, enable/disable and power-up.

With superior THD+N performance and other high performance, the WSP6582C is an ideal device for Hi-Fi system applications.

The WSP6582C is available in 12 Ball Wafer Level Chip Scale Package (WLCSP) with 1.2x1.6x0.5mm. All products is Pb-free and Halogen-free.

Features

- Single supply range operating from 3.0V to 4.5V
- -118dB THD+N into 100kΩ load at 2Vrms
- -114dB THD+N into 32Ω load at 2Vrms
- Signal-to-Noise (SNR) Ratio 132dBA
- 100dB PSRR at 10kHz
- 137dB crosstalk & separation
- Adjust soft-start with external capacitor

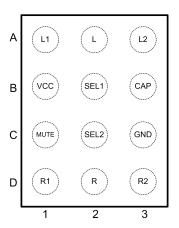
Applications

- Hi-Fi Smartphones and Portable Device
- Hi-Fi SACD/DVD players
- High Quality Home Theaters

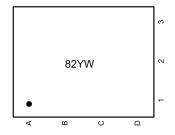
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WLCSP-12B (Bottom view)



Pin configuration (Top view)



Marking

82 = Device code Y = Year code W = Week Code

Order information

Device	Package	Shipping		
WSP6582C-12/TR	WLCSP-12B	3000/Reel&Tape		

Dec, 2016 - Rev. 1.2

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Pin descriptions

Pin Number	Symbol	Descriptions
A1	L1	Left normally closed pin
A2	L	Left common pin
А3	L2	Left normally open pin
B1	VCC	Power supply
B2	SEL1	Select control pin for Left
В3	CAP	Soft-start rising time control with external ceramic capacitor
C1	MUTE	Signal mute control pin
C2	SEL2	Select control pin for Right
C3	GND	Ground
D1	R1	Right normally closed pin
D2	R	Right common pin
D3	R2	Right normally open pin

Block Diagram

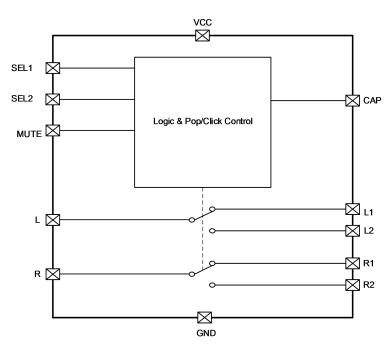


Figure 1. WSP6582C Block Diagram

Function Table

MUTE	SEL1	SEL2	L1	L2	R1	R2
0	0	0	ON	OFF	ON	OFF
0	0	1	ON	OFF	OFF	ON
0	1	0	OFF	ON	ON	OFF
0	1	1	OFF	ON	OFF	ON
1	Х	Х	OFF	OFF	OFF	OFF

Note: X=0 or 1, don't care



Typical Applications

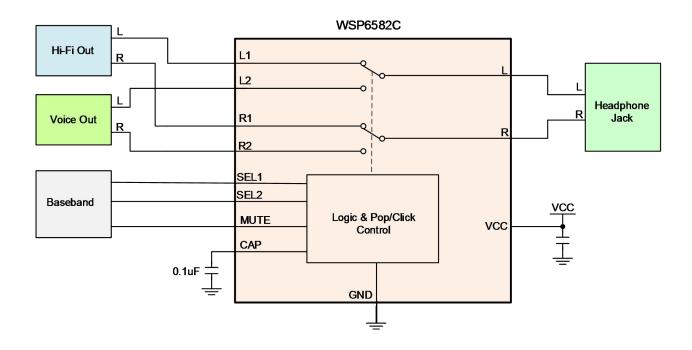


Figure 2. Hi-Fi Phone Application Block Diagram



Absolute Maximum Ratings (1)

Parameter	Symbol	Value	Unit
Supply Voltage	V _{CC}	-0.3 ~ 5.5	V
Digital Control Input Voltage	V _{IN}	-0.3 ~ 5.5	V
Analog Input/Output Voltage (L1,L2,R1,R2,L,R)	Vis	-4.0 ~ 4.0	V
Switch Continuous Current (L1,L2,R1,R2,L,R)	lio	±300	mA
Switch Peak Current (L1,L2,R1,R2,L,R)	1	1500	m 1
(pulsed at 1ms, 10% duty cycle, Max)	I _{IO_PK}	±500	mA
Power Dissipation in Still Air	P _D	250	mW
Storage Temperature Range	T _{STG}	-55 ~ 150	°C
Junction Temperature	TJ	150	°C
Lead Temperature (Soldering, 10 seconds)	TL	260	°C
Thermal Resistance	R _{θJA}	80	°C/W
ESD protection (UDM)	I/O to VCC, I/O to GND	±6000	V
ESD protection (HBM)	I/O to I/O	±4000	V

Recommend operating ratings (2)

Parameter	Symbol	Value	Unit
Supply Voltage	Vcc	3.3 ~ 4.5	V
Digital Control Input Voltage	V _{IN}	0.0 ~ V _{CC}	V
Analog Input/Output Voltage (L1,L2,R1,R2,L,R)	V _{IS}	-3.3 ~ V _{CC}	V
Operating Temperature	T _A	-40 ~ 85	°C

Note:

- 1. "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied.
- 2. The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.

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DC Electronics Characteristics

(Ta=25°C, VCC=3.6V, V_{IS} =2Vrms, R_L =32 Ω , f=1kHz, CAP=0.1uF, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit		
Analog Switch Characteristics	Analog Switch Characteristics							
Analog Signal Range	V _{IS}	VCC: 3.3 ~ 4.2		2.5		Vrms		
On-Resistance	Ron	V _{IS} = -3.3V~+3.3V		0.2		Ω		
Oli-Resistance	KON	I _{OUT} =100mA		0.2		12		
R _{ON} Matching	ΔRon	V _{IS} = -3.3V~+3.3V		0.0015		Ω		
Between Channels	ΔIXON	I _{OUT} =100mA		0.0013				
R _{ON} Flatness	R _{FLAT(ON)}	V _{IS} = -3.3V~+3.3V		0.0015		Ω		
Non Flattiess	TYFLAT(ON)	I _{OUT} =100mA		0.0013				
Dynamic Characteristics								
Total Harmonic Distortion	THD+N	f=10Hz to 22KHz		-118		dB		
Total Harmonic Distortion	וויטווו	V _{IS} =2Vrms @R _L =100kΩ		-110		ub		
Total Harmonic Distortion	THD+N	f=10Hz to 22KHz		-114		dB		
Total Harmonic Distortion	וויטווו	V _{IS} =2Vrms @R _L =32Ω		-114		ub		
		f=10Hz to 500kHz						
Total Harmonic Distortion	THD+N	V _{IS} =1.55Vrms		-104		dB		
		@RL=100kΩ						
		Mode=CCIF 19k+20k						
Intermodulation Distortion	IMD	Ratio=1		-122		dB		
intermodulation distortion	וויוט	V _{IS} =500mVrms		-122		ub		
		@R _L =100kΩ						
Dynamic/Transient	IMD	Mode=DIM100		-103		dB		
Intermodulation Distortion		VIS=1Vrms						
Intermodulation Distortion		@ RL=100kΩ						
		f=10Hz to 22KHz,				dBA		
Signal-to-Noise Ratio	SNR	Inputs grounded		132				
		R_L =32Ω or 100kΩ						
Stereo Channel Imbalance	IMB	f=10Hz to 22KHz,		+0.003		dB		
L1 and R1, L2 and R2	IIVID	R _L =100kΩ		10.003		UD UD		
		f=10Hz to 22KHz,		127				
Off isolation (Muting)	OIRR	$V_L = V_R = 2Vrms$				dB		
On isolation (witting)	OIKK	@R _L =32Ω						
		MUTE=VCC SEL="X"						
		f=10Hz to 22KHz,						
Crosstalk (Channel-to-Channel)	Xtalk	V _{IS} = 2Vrms,		137		dB		
	Alaik	Source Impedance=0Ω				ub		
		R _L = 100kΩ						
	PSRR	f=10kHz,						
Power Supply Ripple Rejection		$V_{IS} = 0.1 Vrms,$		100		dB		
		Inputs grounded						
-3dB Bandwidth	BW	R _L =50Ω		50		MHz		
On-to-Mute Time	T _{TRS-OM}	CAP=0.1uF		50		ns		



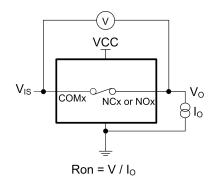
Mute-to-On Time	T _{TRS-MO}	CAP=0.1uF		160		ms
Turn-Off Time	T _{OFF}	V_{IS} =1.5 V , R_L =20 $K\Omega$ MUTE=0		60		ns
Turn-On Time	T _{ON}	V_{IS} =1.5V, R_L =20K Ω MUTE=0				us
Break-Before-Make time	Тввм	V_{IS} =1.5V, R_L =20K Ω MUTE=0		50		us
Lx, Rx Off capacitance	C _{OFF}	f=100kHz, V_{Lx} or $V_{Rx} = V_L$ or $V_R = 0V$		110		pF
L, R On capacitance	Con	$f=100kHz$, V_{Lx} or $V_{Rx} = V_L$ or $V_R = 0V$		130		pF
Power Supply Characteristics						
Supply guiogoph ourrent	Icc	MUTE=0V		190		uA
Supply quiescent current		MUTE=VCC		55		uA
Digital Input Characteristics						
Digital input logic high lovel	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	VCC=3.6~4.5	1.6			V
Digital input logic high level	V _{IH}	VCC=3.0~3.6	1.5			V
Digital input logic low lovel	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	VCC=3.6~4.5			0.5	V
Digital input logic low level	V _{IL}	VCC=3.0~3.6			0.4	V
Digital Input leakage current	I _{IN}				±2.0	uA
SEL pull-down resistor	R _{PD}			4		МΩ
MUTE pull-up resistor	R _{PU}			4		МΩ

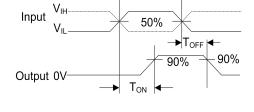
Note:

- 3. Flatness is defined as the difference between maximum and minimum value of ON-resistance at the specified analog signal voltage points.
- 4. R_{ON} matching between channels is calculated by subtracting the channel with the highest max Ron value from the channel with lowest max ron value.
- **5.** Crosstalk is inversely proportional to source impedance.



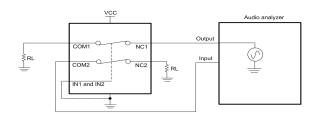
Test Circuits

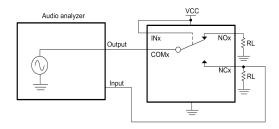




ON-Resistance (RoN)

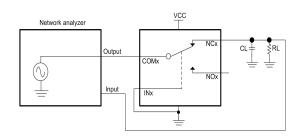
ON/OFF Time Waveforms (Ton / Toff)

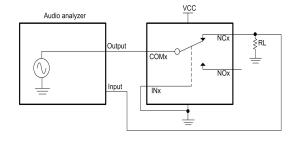




Crosstalk (Xtalk)

Off isolation (OIRR)





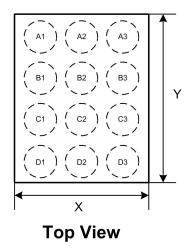
Bandwidth (BW)

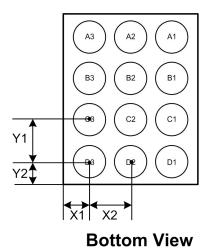
THD+N

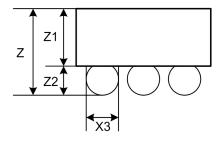


Package outline dimensions

WLCSP-12B







Side View

Oh a l	Dimensions in millimeter				
Symbol	Min.	Тур.	Max.		
X	1.180	1.205	1.230		
Υ	1.610	1.635	1.660		
X1		0.077			
X2		0.400			
X3	0.230	0.250	0.270		
Y1		0.400			
Y2		0.077			
Z	0.480	0.535	0.590		
Z1	0.305	0.330	0.355		
Z2	0.145	0.165	0.185		

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